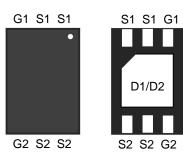


## Dual N-Channel 20 V (D-S) Power MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (mΩ)(Typ.)	I <sub>D</sub> (A)ª	Q <sub>g</sub> (Typ.)		
20	12.5 at V <sub>GS</sub> = 4.5 V	8.2	12 nC		
20	15.6 at V <sub>GS</sub> = 2.5 V	0.2			

#### **DFN2X3-6L Pin Configuration**



Top View

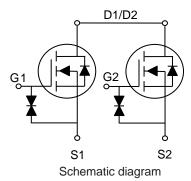
Bottom View

#### FEATURES

- DT- Trench Power MOSFET
- + 100  $\%~{\rm R_g}$  and UIS Tested
- ESD Rating: HBM 2KV
- Low Gate Charge

### APPLICATIONS

- · Load Switch
- POL Applications
- Li-Battery Protection



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V <sub>DS</sub>	20	v		
Gate-Source Voltage	V <sub>GS</sub>	± 12	V		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T <sub>A</sub> = 25 °C		8.2		
	T <sub>A</sub> = 100 °C		6.1	А	
Pulsed Drain Current <sup>b</sup>	I <sub>DM</sub>	32			
Single Avalanche Energy		E <sub>AS</sub>	27	mJ	
Maximum Dawer Dissinctions	T <sub>A</sub> = 25 °C	D	1.6	w	
Maximum Power Dissipation <sup>c</sup>	T <sub>A</sub> = 100 °C		0.64	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to + 150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (Drain)	R <sub>thJA</sub>	78	°C/W		

#### Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of ReuA is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with Ta=25 °C.



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	·						
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$		-	-	v	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	0.5	-	1	v	
Gate-Body Leakage			-	-	± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 20 V, V_{GS} = 0 V$	-	-	1		
	I <sub>DSS</sub>	$V_{DS} = 16 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$	-	-	100	μA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	8.2	-	-	А	
Drain-Source On-State Resistance <sup>a</sup>	Pro( )	$V_{GS}$ = 4.5 V, I <sub>D</sub> = 5 A	-	12.5	15	mΩ	
	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 5 \text{ A}$	-	15.6	21		
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 5 V, I_{D} = 5 A$	-	13	-	S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>		-	680	-	pF	
Output Capacitance	C <sub>oss</sub>	$V_{GS}$ = 0 V, $V_{DS}$ = 10 V, f = 1 MHz	-	155	-		
Reverse Transfer Capacitance	C <sub>rss</sub>		-	92	-		
Total Gate Charge <sup>c</sup>	Qg		-	12	-		
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 5 A	-	1.9	-	nC	
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>		-	2.4	-		
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>		-	7.5	-		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}, \text{ R}_{g} = 3 \Omega$	-	20	-		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	V <sub>GS</sub> = 4.5 V	-	49	-	ns	
Fall Time <sup>c</sup>	t <sub>f</sub>		-	32	-		
Drain-Source Body Diode Ratings and	Characterist	<b>ics</b> <sup>b</sup> (T <sub>A</sub> = 25 °C)					
Continuous Source-Drain Diode Current	۱ <sub>S</sub>	T <sub>A</sub> = 25 °C	-	-	8.2	А	
Pulsed Current	I <sub>SM</sub>		-	-	32	А	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 1 A, V <sub>GS</sub> = 0 V	-	-	1.2	V	
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#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

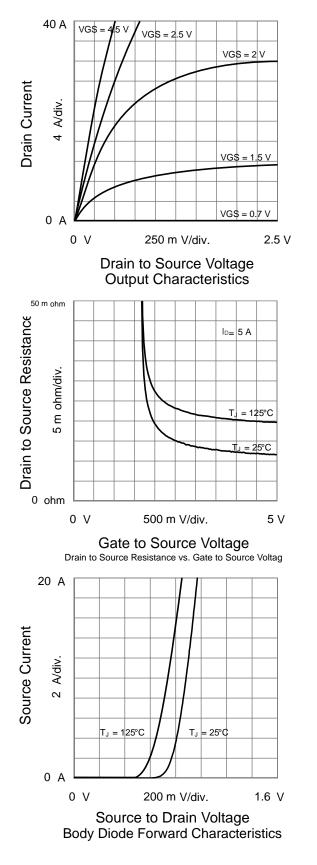
b. Guaranteed by design, not subject to production testing.

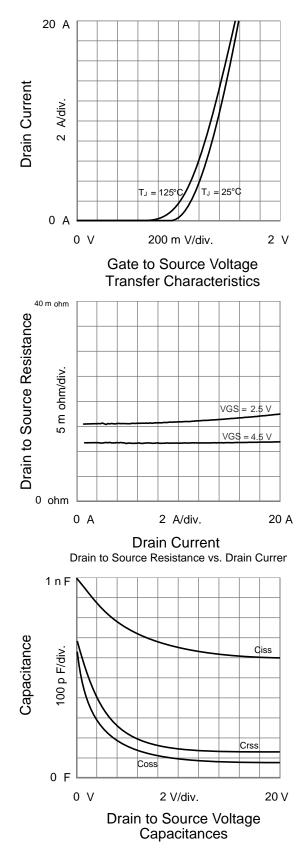
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those in dicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



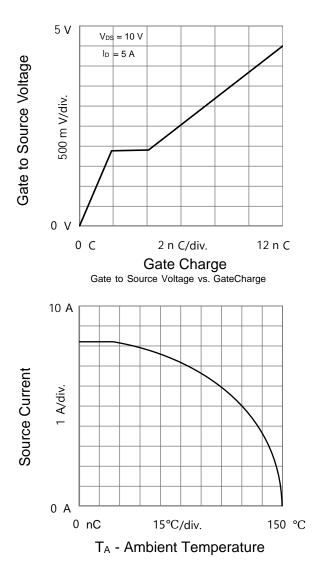
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

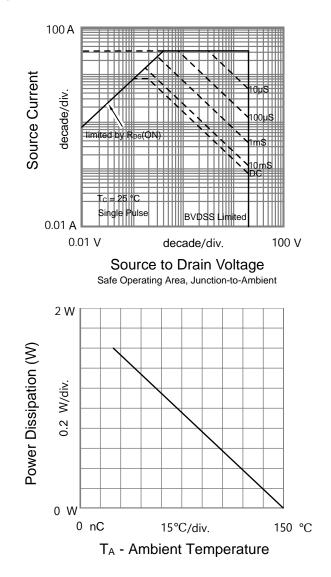






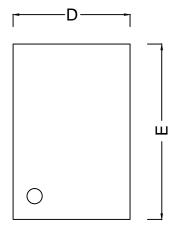
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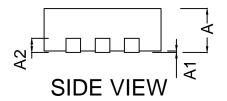




# DFN2X3-6L-D PACKAGE OUTLINE



TOP VIEW



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**BOTTOM VIEW** 

SYMBOL		mm	
STNDOL	MIN	TYP	MAX
А	0.70	0.75	0.80
A1	0.00	0.02	0.05
A2	0.203 REF		
b	0.20	0.25	0.30
D	1.90	2.00	2.10
E	2.90	3.00	3.10
е	0.500 BSC		
D1	1.45	1.50	1.55
E1	1.65	1.70	1.75
k	0.25	0.30	0.35
L	0.30	0.35	0.40



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